

N-Channel 60 V (D-S) MOSFET

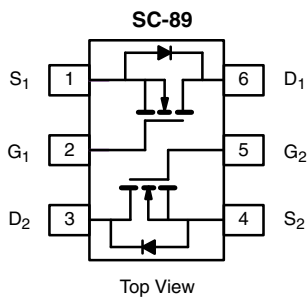
| PRODUCT SUMMARY | | | |
|-------------------|---------------------------|------------------|------------|
| $V_{DS(min)}$ (V) | $R_{DS(on)}$ (Ω) | $V_{GS(th)}$ (V) | I_D (mA) |
| 60 | 1.40 at $V_{GS} = 10$ V | 1 to 2.5 | 500 |

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- Low On-Resistance: 1.40 Ω
- Low Threshold: 2 V (typ.)
- Low Input Capacitance: 30 pF
- Fast Switching Speed: 15 ns (typ.)
- Low Input and Output Leakage
- ESD Protected: 2000 V
- Miniature Package
- Compliant to RoHS Directive 2002/95/EC



RoHS
COMPLIANT
HALOGEN
FREE



Marking Code: E

BENEFITS

- Low Offset Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Error Voltage
- Small Board Area

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Battery Operated Systems
- Solid-State Relays

Ordering Information: Si1026X-T1-GE3 (Lead (Pb)-free and Halogen-free)

| ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted) | | | | | |
|---|----------------|---------------|--------------|------|----|
| Parameter | Symbol | 5 s | Steady State | Unit | |
| Drain-Source Voltage | V_{DS} | 60 | | V | |
| Gate-Source Voltage | V_{GS} | ± 20 | | | |
| Continuous Drain Current ($T_J = 150$ °C) ^a | I_D | $T_A = 25$ °C | 320 | 305 | mA |
| | | $T_A = 85$ °C | 230 | 220 | |
| Pulsed Drain Current ^b | I_{DM} | - 650 | | | |
| Continuous Source Current (Diode Conduction) ^a | I_S | 450 | 380 | | |
| Maximum Power Dissipation ^a | P_D | $T_A = 25$ °C | 280 | 250 | mW |
| | | $T_A = 85$ °C | 145 | 130 | |
| Operating Junction and Storage Temperature Range | T_J, T_{stg} | - 55 to 150 | | °C | |
| Gate-Source ESD Rating (HBM, Method 3015) | ESD | 2000 | | V | |

Notes:

- Surface mounted on FR4 board.
- Pulse width limited by maximum junction temperature.

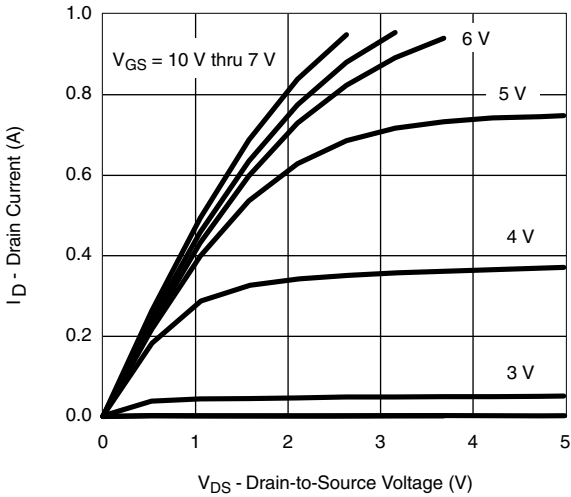
| SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted) | | | | | | |
|--|--------------|--|------|------|-----------|---------------|
| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | V_{DS} | $V_{GS} = 0\text{ V}$, $I_D = 10\text{ }\mu\text{A}$ | 60 | | | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 0.25\text{ mA}$ | 1 | | 2.5 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0\text{ V}$, $V_{GS} = \pm 10\text{ V}$ | | | ± 150 | nA |
| | | $V_{DS} = 0\text{ V}$, $V_{GS} = \pm 5\text{ V}$ | | | ± 50 | |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 60\text{ V}$, $V_{GS} = 0\text{ V}$ | | | 1 | μA |
| | | $V_{DS} = 60\text{ V}$, $V_{GS} = 0\text{ V}$, $T_J = 85\text{ }^\circ\text{C}$ | | | 10 | |
| On-State Drain Current ^a | $I_{D(on)}$ | $V_{DS} = 10\text{ V}$, $V_{GS} = 4.5\text{ V}$ | 500 | | | mA |
| | | $V_{DS} = 7.5\text{ V}$, $V_{GS} = 10\text{ V}$ | 800 | | | |
| Drain-Source On-Resistance ^a | $R_{DS(on)}$ | $V_{GS} = 4.5\text{ V}$, $I_D = 200\text{ mA}$ | | | 3.0 | Ω |
| | | $V_{GS} = 10\text{ V}$, $I_D = 500\text{ mA}$ | | | 1.40 | |
| | | $V_{GS} = 10\text{ V}$, $I_D = 500\text{ mA}$, $T_J = 125\text{ }^\circ\text{C}$ | | | 2.50 | |
| Forward Transconductance ^a | g_{fs} | $V_{DS} = 10\text{ V}$, $I_D = 200\text{ mA}$ | | 200 | | mS |
| Diode Forward Voltage ^a | V_{SD} | $V_{GS} = 0\text{ V}$, $I_S = 200\text{ mA}$ | | | 1.40 | V |
| Dynamic^b | | | | | | |
| Total Gate Charge | Q_g | $V_{DS} = 10\text{ V}$, $I_D = 250\text{ mA}$, $V_{GS} = 4.5\text{ V}$ | | 600 | | pC |
| Gate-Source Charge | Q_{gs} | | | 120 | | |
| Gate-Drain Charge | Q_{gd} | | | 225 | | |
| Input Capacitance | C_{iss} | $V_{DS} = 25\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$ | | 30 | | pF |
| Output Capacitance | C_{oss} | | | 6 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 3 | | |
| Switching^{b, c} | | | | | | |
| Turn-On Time | $t_{(on)}$ | $V_{DD} = 30\text{ V}$, $R_L = 150\text{ }\Omega$ | | 15 | | ns |
| Turn-Off Time | $t_{(off)}$ | $I_D = 200\text{ mA}$, $V_{GEN} = 10\text{ V}$, $R_g = 10\text{ }\Omega$ | | 20 | | |

Notes:

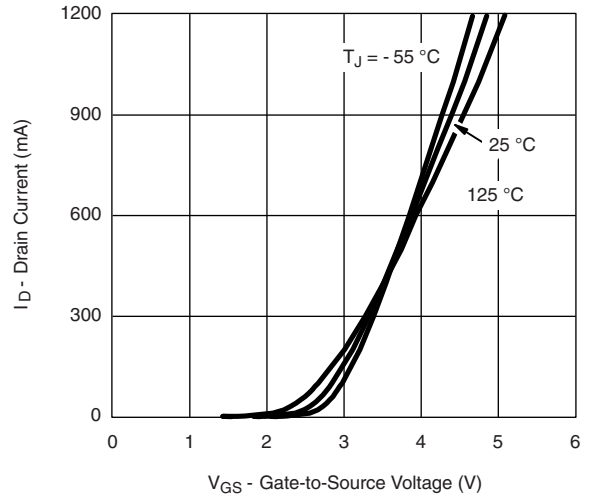
- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- For DESIGN AID ONLY, not subject to production testing.
- Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

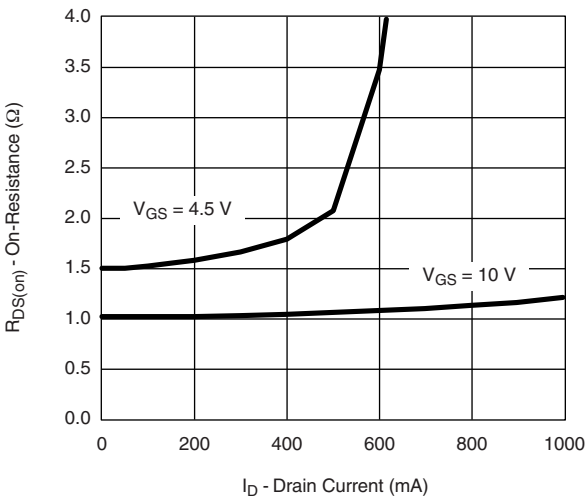
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



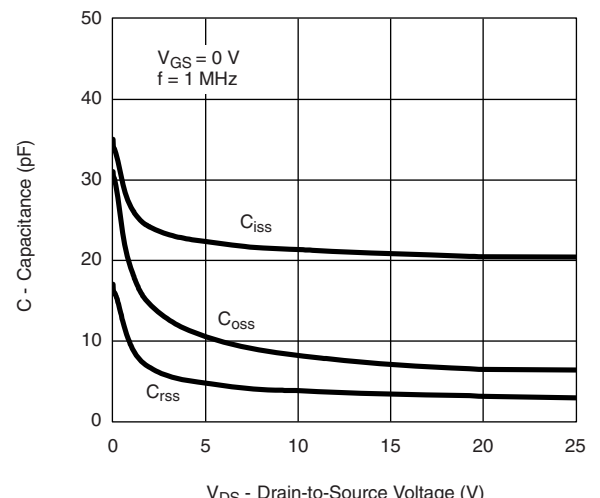
Output Characteristics



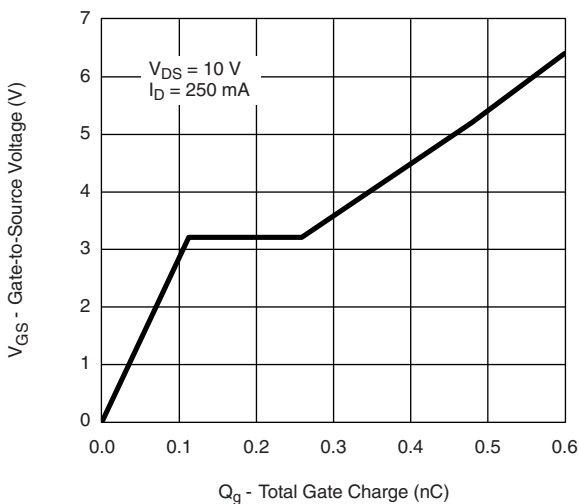
Transfer Characteristics



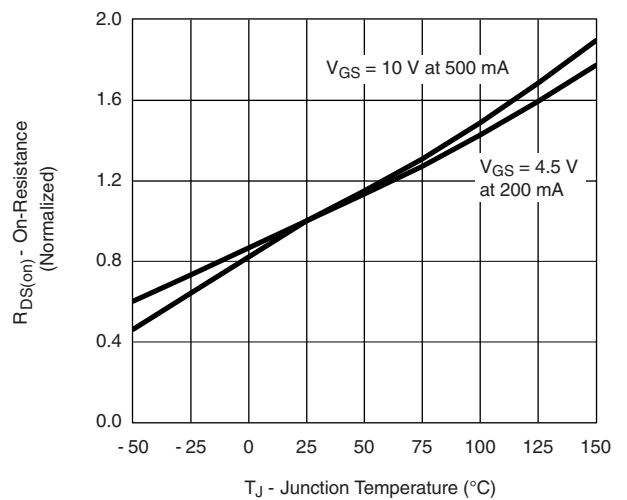
On-Resistance vs. Drain Current



Capacitance

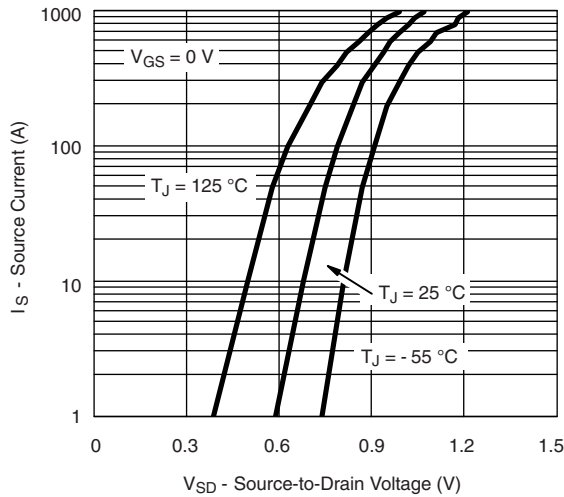


Gate Charge

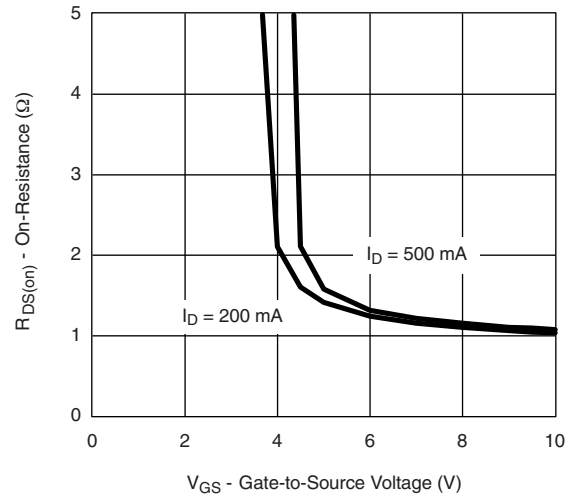


On-Resistance vs. Junction Temperature

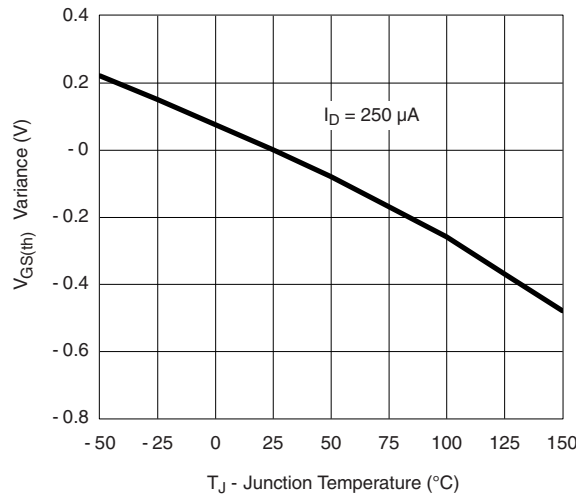
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



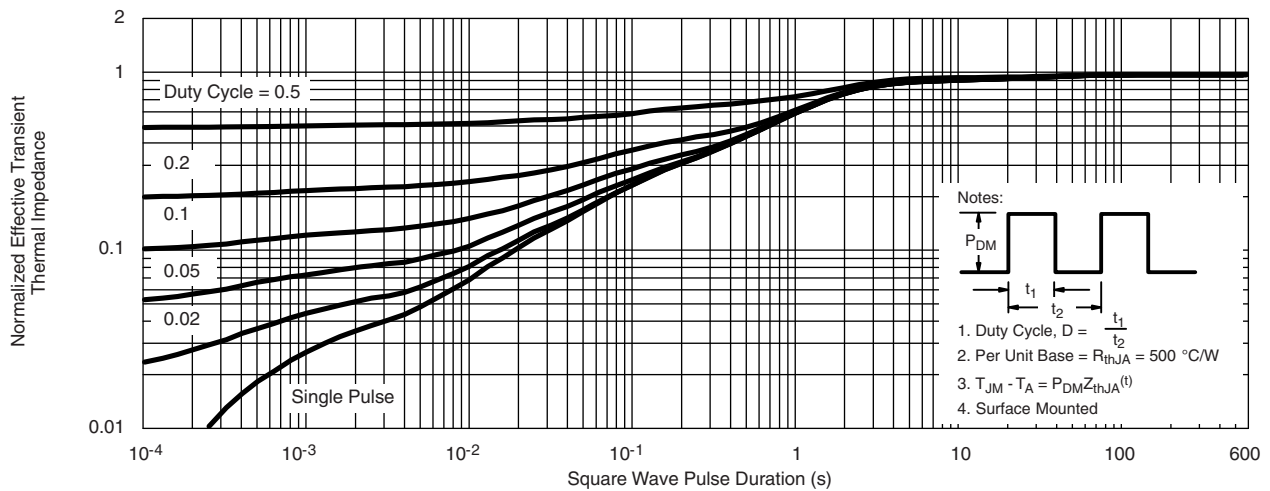
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



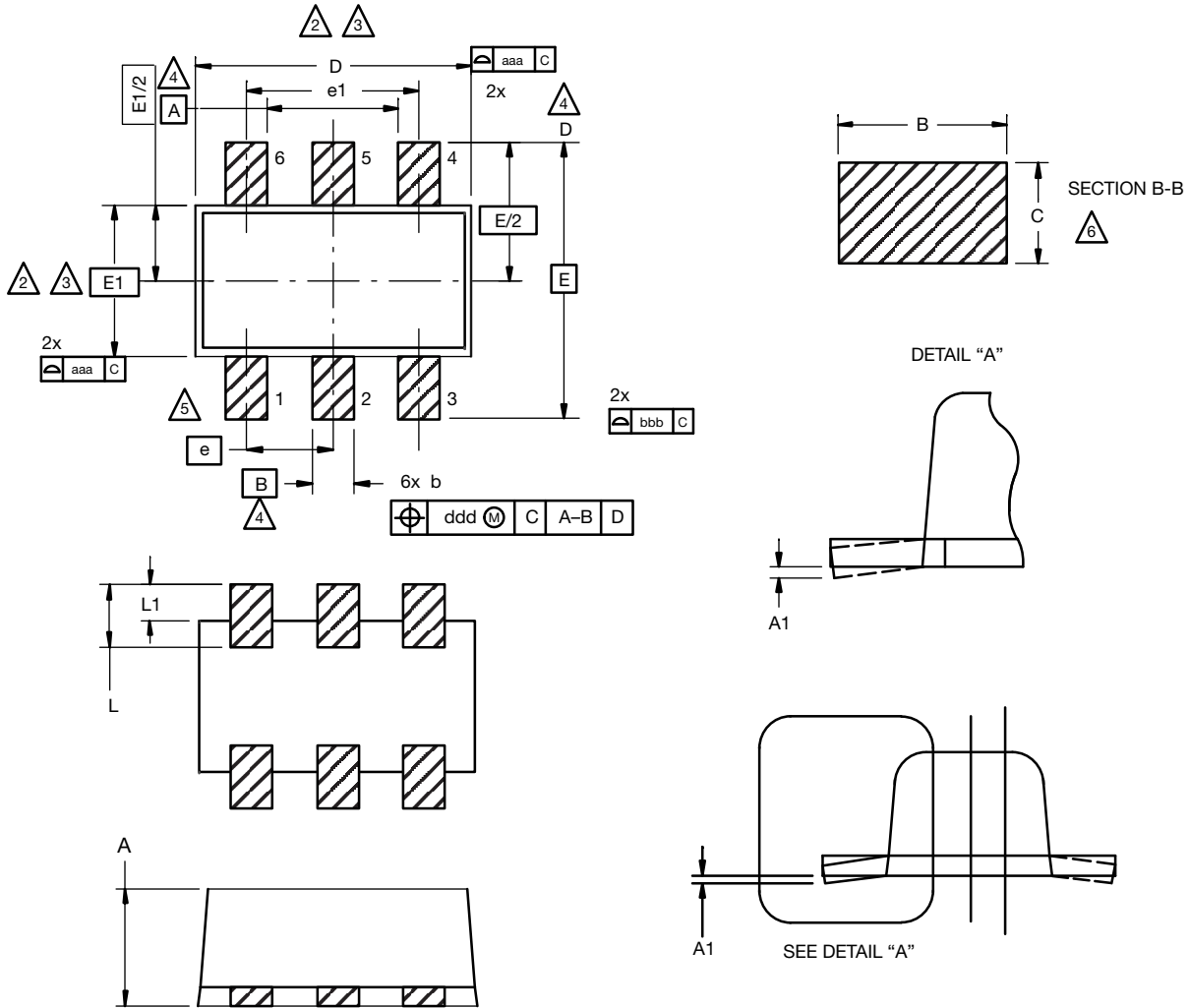
Threshold Voltage Variance Over Temperature



Normalized Thermal Transient Impedance, Junction-to-Ambient

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SC-89 6-Leads (SOT-563F)



Notes

1. Dimensions in millimeters.

⚠ Dimension D does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.

⚠ Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

⚠ Datums A, B and D to be determined 0.10 mm from the lead tip.

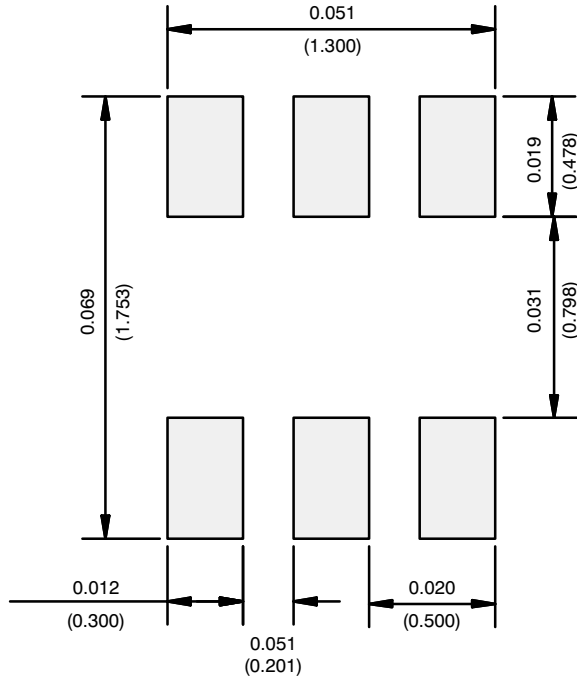
⚠ Terminal numbers are shown for reference only.

⚠ These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

| DIM. | MILLIMETERS | | |
|------|-------------|------|------|
| | MIN. | NOM. | MAX. |
| A | 0.56 | 0.58 | 0.60 |
| A1 | 0 | 0.02 | 0.10 |
| b | 0.15 | 0.22 | 0.30 |
| c | 0.10 | 0.14 | 0.18 |
| D | 1.50 | 1.60 | 1.70 |
| E | 1.50 | 1.60 | 1.70 |
| E1 | 1.15 | 1.20 | 1.25 |
| e | 0.45 | 0.50 | 0.55 |
| e1 | 0.95 | 1.00 | 1.05 |
| L | 0.25 | 0.35 | 0.50 |
| L1 | 0.10 | 0.20 | 0.30 |

C14-0439-Rev. C, 11-Aug-14
DWG: 5880

RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

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